



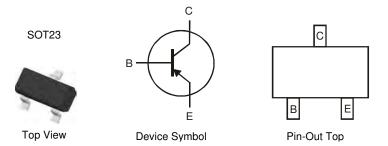
60V LOW V_{CE(sat)} PNP SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Ideal for Medium Power Amplification and Switching
- "Lead Free", RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe.
 Solderable per MIL-STD-202, Method 208
- Weight: 0.008 grams (approximate)



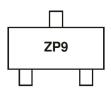
Ordering Information (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DSS5160T-7	ZP9	7	8mm	3,000

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com
- 3. For packaging details, go to our website at http://www.diodes.com

Marking Information



ZP9 = Product Type Marking Code



Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-80	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Base Voltage	V _{EBO}	-5	V
Continuous Collector Current	Ic	-1	Α
Peak Pulse Collector Current	Ісм	-2	Α
Base Current (DC)	I _B	-300	mA
Peak Base Current	I _{BM}	-1	A

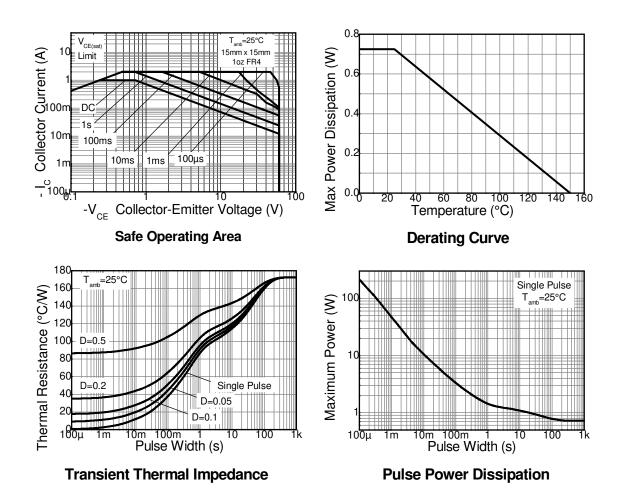
Thermal Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	725	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\scriptscriptstyle{ hetaJA}}$	172	°C/W
Thermal Resistance, Junction to Ambient Air (Note 4)	$R_{ heta JA}$	79	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes:

- 4. Operated under pulsed conditions: pulse width \leq 100ms, duty cycle \leq 0.25.
- 5. Device mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

Thermal Characteristics



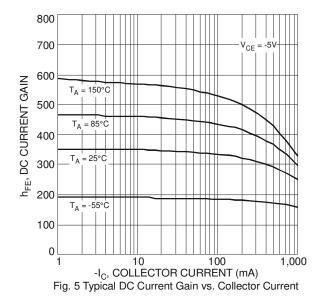


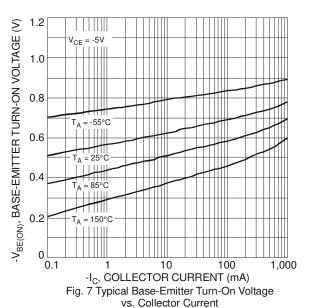
Electrical Characteristics @T_A = 25°C unless otherwise specified

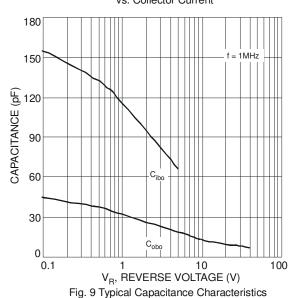
Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
Collector-Base Breakdown Voltage	BV _{CBO}	-80	_	_	V	$I_C = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 6)	BV _{CEO}	-60	_	_	V	$I_C = -10 \text{mA}$
Emitter-Base Breakdown Voltage	BV _{EBO}	-5			V	$I_E = -100 \mu A$
Collector-Base Cutoff Current	I _{CBO}			-100	nA	$V_{CB} = -20V, I_{E} = 0$
Collector-base Cuton Current				-50	μΑ	$V_{CB} = -20V, I_E = 0, T_A = 150$ °C
Emitter-Base Cutoff Current	I _{EBO}			-100	nA	$V_{EB} = -5V, I_C = 0$
		200				$V_{CE} = -5V$, $I_C = -1mA$
DC Current Gain (Note 6)	h _{FE}	150				$V_{CE} = -5V, I_{C} = -500mA$
		100				$V_{CE} = -5V, I_{C} = -1A$
				-175		$I_C = -100 \text{mA}, I_B = -1 \text{mA}$
Collector-Emitter Saturation Voltage (Note 6)	V _{CE(sat)}			-180	mV	$I_C = -500 \text{mA}, I_B = -50 \text{mA}$
			_	-340		$I_C = -1A$, $I_B = -100mA$
Equivalent On-Resistance	R _{CE(sat)}			340	mΩ	$I_E = -1A$, $I_B = -100mA$
Base-Emitter Saturation Voltage	V _{BE(sat)}			-1.1	V	$I_C = -1A$, $I_B = -50mA$
Base-Emitter Turn-on Voltage	V _{BE(on)}			-0.9	V	$V_{CE} = -5V, I_{C} = -1A$
Transition Frequency	f _T	150	_	_	MHz	$V_{CE} = -10V, I_{C} = -50mA,$ f = 100MHz
Output Capacitance	C _{ob}			15	pF	$V_{CB} = -10V$, $f = 1MHz$
Turn-On Time	ton		75	_	ns	
Delay Time	t _d		35	_	ns	
Rise Time	t _r		40	_	ns	$V_{CC} = -10V, I_{C} = -0.5A,$
Turn-Off Time	t _{off}		265	_	ns	$I_{B1} = I_{B2} = -25\text{mA}$
Storage Time	ts	_	230		ns	
Fall Time	t _f	_	35	_	ns	

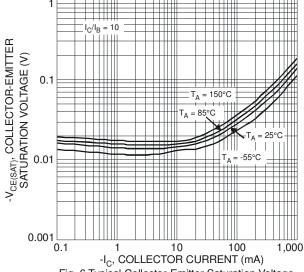
Notes: 6. Measured under pulsed conditions. Pulse width = $300\mu s$. Duty cycle $\leq 2\%$.











-I_C, COLLECTOR CURRENT (mA)
Fig. 6 Typical Collector-Emitter Saturation Voltage
vs. Collector Current

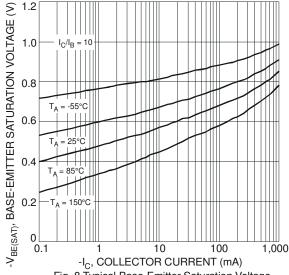
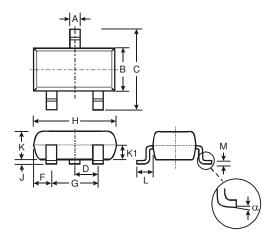


Fig. 8 Typical Base-Emitter Saturation Voltage vs. Collector Current

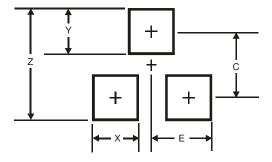


Package Outline Dimensions



SOT23				
Dim	Min	Max	Тур	
Α	0.37	0.51	0.40	
В	1.20	1.40	1.30	
С	2.30	2.50	2.40	
D	0.89	1.03	0.915	
F	0.45	0.60	0.535	
G	1.78	2.05	1.83	
Н	2.80	3.00	2.90	
J	0.013	0.10	0.05	
K	0.903	1.10	1.00	
K1	-	-	0.400	
L	0.45	0.61	0.55	
M	0.085	0.18	0.11	
α	0°	8°	-	
All Dimensions in mm				

Suggested Pad Layout



Dimensions	Value (in mm)		
Z	2.9		
Х	0.8		
Υ	0.9		
С	2.0		
Е	1.35		



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